



# BUJ302AD

NPN power transistor

Rev. 01 — 28 March 2011

Product data sheet

## 1. Product profile

### 1.1 General description

High-voltage, high-speed planar-passivated NPN power switching transistor in a SOT428 (DPAK) surface mounted package.

### 1.2 Features and benefits

- Fast switching
- High voltage capability
- Low thermal resistance
- Surface-mountable package

### 1.3 Applications

- DC-to-DC converters
- High-frequency electronic lighting ballast applications
- Inverters
- Motor control systems

### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_C$	collector current	see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a> ; see <a href="#">Figure 4</a>	-	-	4	A
$P_{tot}$	total power dissipation	$T_{mb} \leq 25\text{ °C}$ ; see <a href="#">Figure 3</a>	-	-	80	W
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	-	-	1050	V
<b>Static characteristics</b>						
$h_{FE}$	DC current gain	$I_C = 0.1\text{ A}$ ; $V_{CE} = 5\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; see <a href="#">Figure 11</a>	[1] 48	66	100	
		$I_C = 0.8\text{ A}$ ; $V_{CE} = 3\text{ V}$ ; $T_{mb} = 25\text{ °C}$ ; see <a href="#">Figure 12</a>	[1] 25	42	50	

[1] Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\text{ %}$



## 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B	base		
2	C	collector <sup>[1]</sup>		
3	E	emitter		
mb	C	mounting base; connected to collector		

**SOT428 (DPAK)**

[1] it is not possible to make a connection to pin 2 of the SOT428 (DPAK) package

## 3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BUJ302AD	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CESM}$	collector-emitter peak voltage	$V_{BE} = 0\text{ V}$	-	1050	V
$V_{CEO}$	collector-emitter voltage	$I_B = 0\text{ A}$	-	400	V
$I_C$	collector current	see <a href="#">Figure 1</a> ; see <a href="#">Figure 2</a> ; see <a href="#">Figure 4</a>	-	4	A
$I_{CM}$	peak collector current		-	8	A
$I_B$	base current		-	2	A
$I_{BM}$	peak base current		-	4	A
$P_{tot}$	total power dissipation	$T_{mb} \leq 25\text{ °C}$ ; see <a href="#">Figure 3</a>	-	80	W
$T_{stg}$	storage temperature		-65	150	°C
$T_j$	junction temperature		-	150	°C
$V_{EBO}$	emitter-base voltage	$I_C = 0\text{ A}$ ; $I_E = 2\text{ A}$ ; $t_p < 10\text{ ms}$	-	24	V

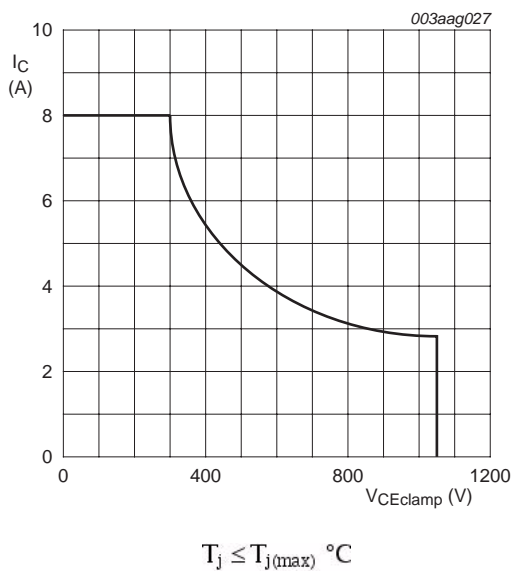
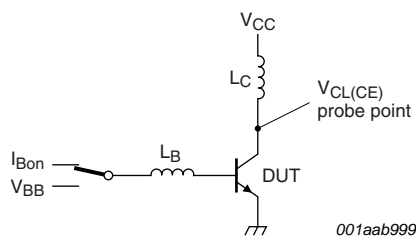
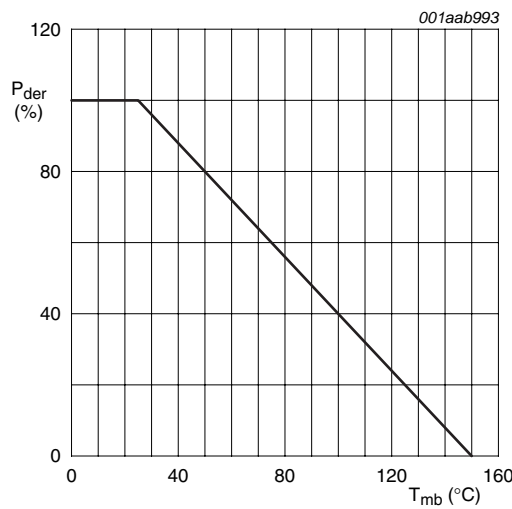


Fig 1. Reverse bias safe operating area



$V_{CL(CE)} \leq 1000 \text{ V}; V_{CC} = 150 \text{ V}; V_{BB} = -5 \text{ V};$   
 $L_B = 1 \text{ } \mu\text{H}; L_C = 200 \text{ } \mu\text{H}$

Fig 2. Test circuit for reverse bias safe operating area



$$P_{der} = \frac{P_{tot}}{P_{tot(25^\circ\text{C})}} \times 100 \%$$

Fig 3. Normalized total power dissipation as a function of mounting base temperature



5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	see <a href="#">Figure 5</a>	-	-	1.56	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient in free air		-	60	-	K/W

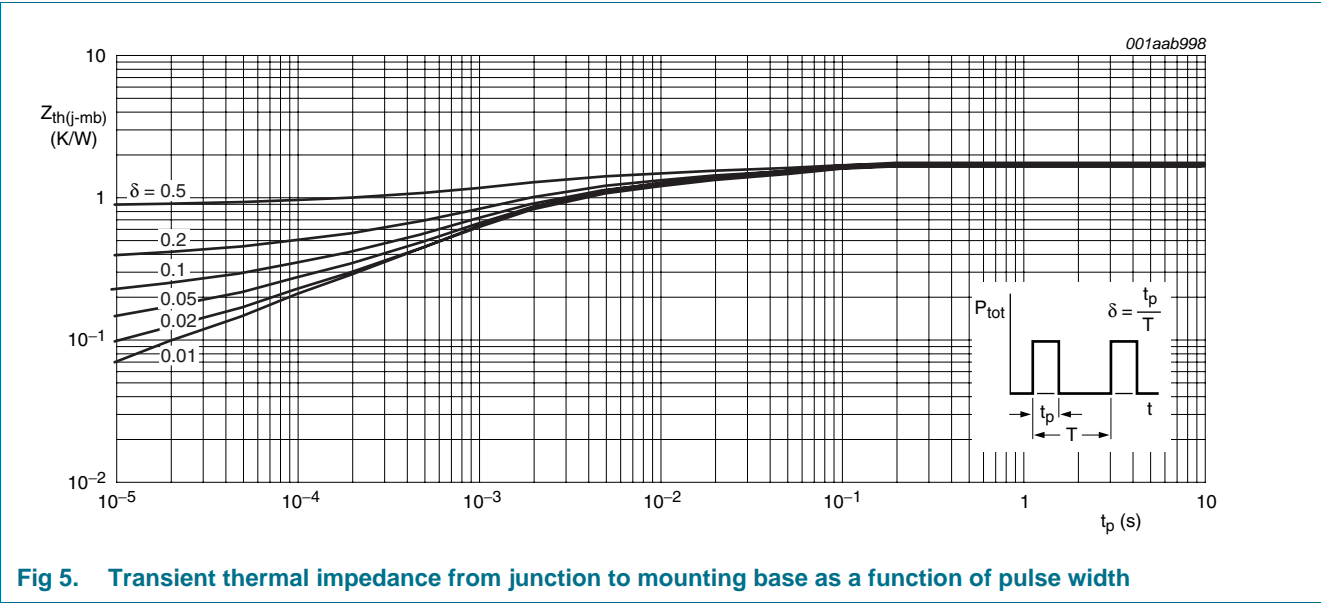


Fig 5. Transient thermal impedance from junction to mounting base as a function of pulse width

## 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Static characteristics							
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>BE</sub> = 0 V; V <sub>CE</sub> = 1050 V; T <sub>mb</sub> = 25 °C	-	0.2	10	μA	
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 400 V; I <sub>B</sub> = 0 A; T <sub>mb</sub> = 25 °C	-	10	250	mA	
V <sub>(BR)EBO</sub>	open-collector emitter-base breakdown voltage	I <sub>B</sub> = 1 mA; I <sub>C</sub> = 0 A; T <sub>mb</sub> = 25 °C	15	19	-	V	
V <sub>CEOsus</sub>	collector-emitter sustaining voltage	I <sub>B</sub> = 0 A; I <sub>C</sub> = 10 mA; L <sub>C</sub> = 25 mH; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 6</a> ; see <a href="#">Figure 7</a>	<a href="#">[1]</a>	400	470	-	V
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 0.2 A; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 8</a> ; see <a href="#">Figure 9</a>	<a href="#">[1]</a>	-	0.15	0.5	V
		I <sub>C</sub> = 3.5 A; I <sub>B</sub> = 1 A; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 8</a> ; see <a href="#">Figure 9</a>	<a href="#">[1]</a>	-	0.6	1.5	V
V <sub>BEsat</sub>	base-emitter saturation voltage	I <sub>C</sub> = 3.5 A; I <sub>B</sub> = 1 A; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 10</a>	<a href="#">[1]</a>	-	1.1	1.5	V
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 0.1 A; V <sub>CE</sub> = 5 V; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 11</a>	<a href="#">[1]</a>	48	66	100	
		I <sub>C</sub> = 0.8 A; V <sub>CE</sub> = 3 V; T <sub>mb</sub> = 25 °C; see <a href="#">Figure 12</a>	<a href="#">[1]</a>	25	42	50	
Dynamic characteristics							
t <sub>s</sub>	storage time	I <sub>C</sub> = 2.5 A; I <sub>Bon</sub> = 0.5 A; I <sub>Boff</sub> = -0.5 A; R <sub>L</sub> = 60 Ω; V <sub>BB</sub> = -5 V; T <sub>mb</sub> = 25 °C; resistive load; t <sub>p</sub> = 300 μs; see <a href="#">Figure 13</a> ; see <a href="#">Figure 14</a>	-	-	3.5	μs	
t <sub>f</sub>	fall time		-	-	500	ns	

[1] Pulse test: pulse duration  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$

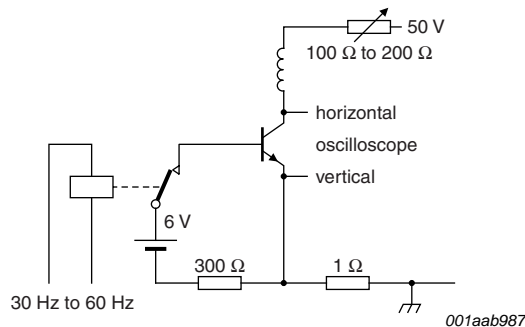


Fig 6. Test circuit for collector-emitter sustaining voltage

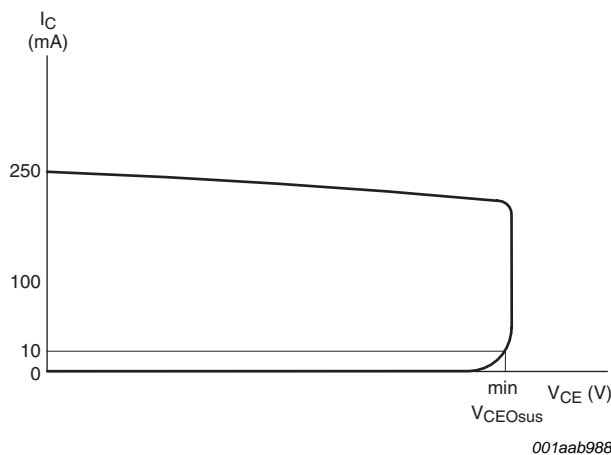


Fig 7. Oscilloscope display for collector-emitter sustaining voltage test waveform

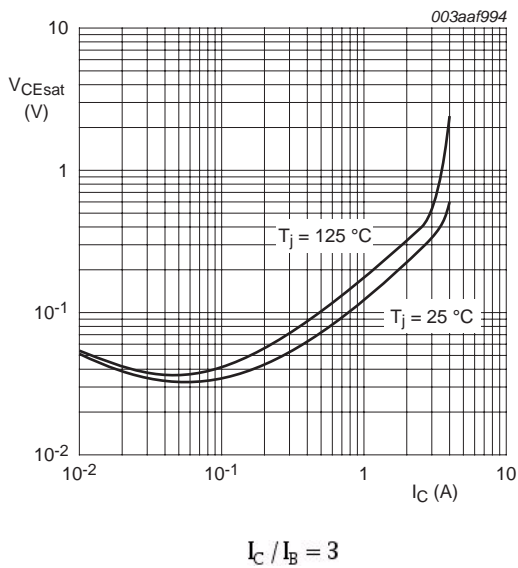


Fig 8. Collector-emitter saturation voltage as a function of collector current; typical values

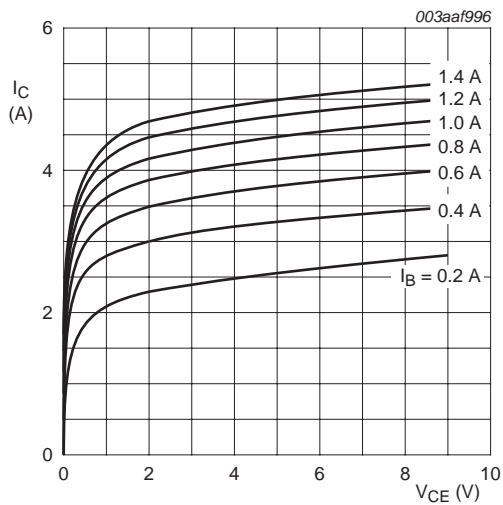


Fig 9. Collector current as a function of collector-emitter voltage; typical values

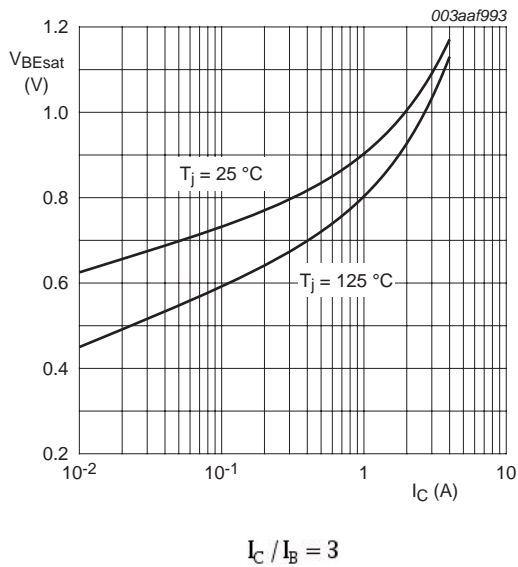


Fig 10. Base-emitter saturation voltage as a function of collector current; typical values

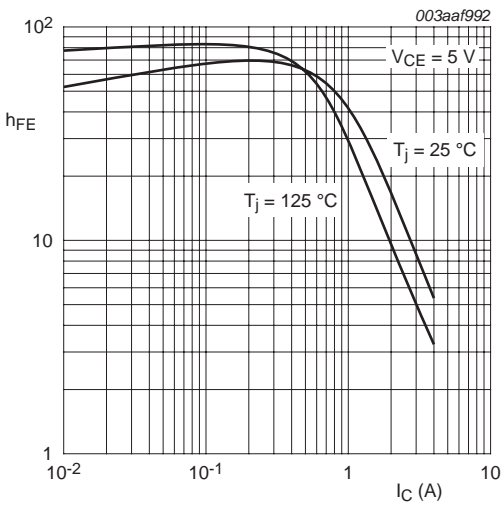


Fig 11. DC current gain as a function of collector current; typical values

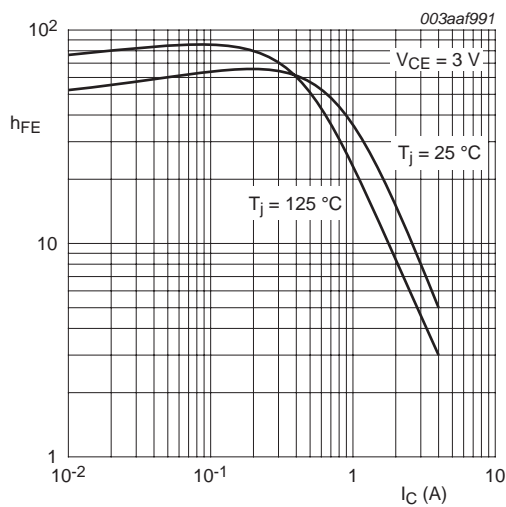
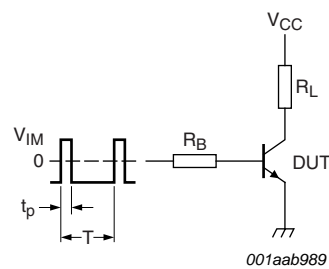


Fig 12. DC current gain as a function of collector current; typical values



$V_{IM} = -6\text{ to }+8\text{ V}$ ;  $V_{CC} = 250\text{ V}$ ;  $t_p = 20\text{ }\mu\text{s}$ ;  $\delta = \frac{t_p}{T} = 0.01$   
 $R_B$  and  $R_L$  calculated from  $I_{Con}$  and  $I_{Bon}$  requirements.

Fig 13. Test circuit for resistive load switching

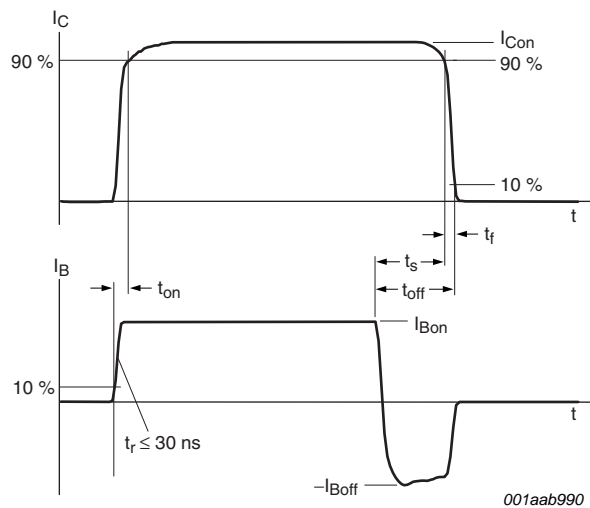


Fig 14. Switching times waveforms for resistive load



## 7. Package outline

Plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)

SOT428

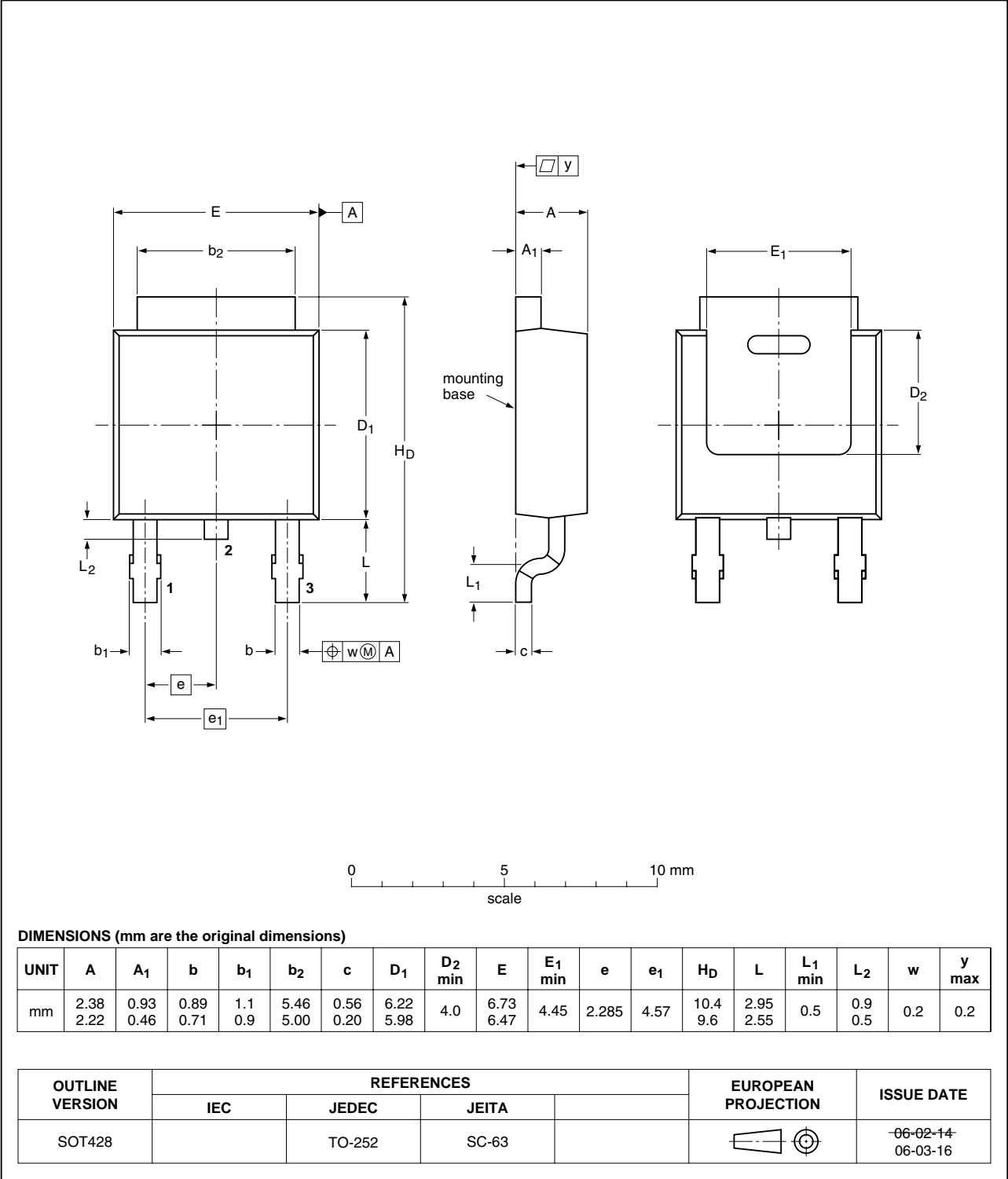


Fig 15. Package outline SOT428 (DPAK)

8. Soldering

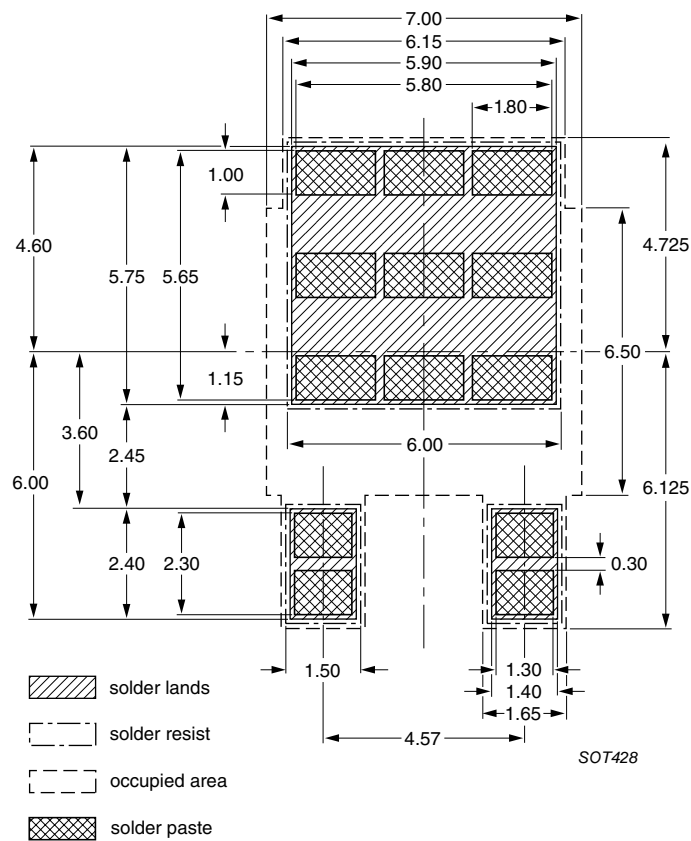


Fig 16. Reflow soldering footprint for SOT428 (DPAK)

## 9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BUJ302AD v.1	20110328	Product data sheet	-	-

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Document status <sup>[1] [2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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Date of release: 28 March 2011

Document identifier: BUJ302AD